

# **Vishay Siliconix**

## **High-Voltage Switchmode Regulator**

#### **FEATURES**

- 10- to 120-V Input Range
- Current-Mode Control
- On-Chip 200-V, 5-Ω MOSFET Switch
   Internal Start-Up Circuit
- SHUTDOWN and RESET
- High Efficiency Operation (>80%)
- Internal Oscillator (1 MHz)

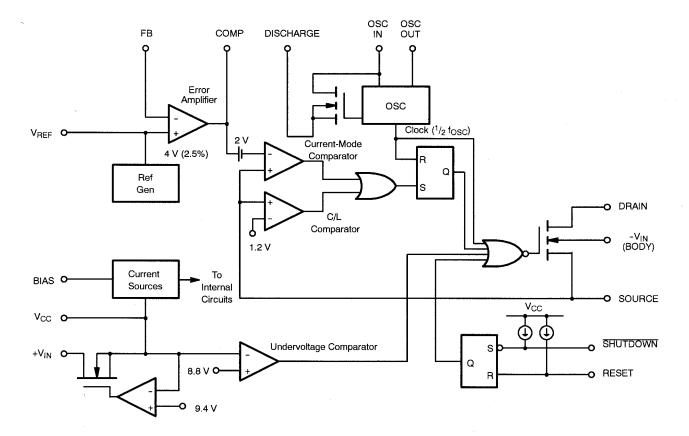
#### **DESCRIPTION**

The Si9104 high-voltage switchmode regulator is a monolithic BiC/DMOS integrated circuit which contains most of the components necessary to implement a high-efficiency dc-todc converter up to 3 watts. It can either be operated from a low-voltage dc supply, or directly from a 10- to 120-V unregulated dc power source.

This device may be used with an appropriate transformer to implement most single-ended isolated power converter topologies (i.e., flyback and forward).

The Si9104 is available in a 16-pin wide-body SOIC and is specified over the D suffix (-40 to 85°C) temperature range.

#### **FUNCTIONAL BLOCK DIAGRAM**



# Si9104

# Vishay Siliconix



#### **ABSOLUTE MAXIMUM RATINGS**

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RECOMMENDED OPERATING RANGE           Voltages Referenced to -V <sub>IN</sub> 10 V to 13.5 V           +V <sub>IN</sub> 10 V to 120 V           fosc         40 kHz to 1 MHz	$\begin{array}{cccccccccccccccccccccccccccccccccccc$

SPECIFICATIONS <sup>a</sup>								
		Test Conditions Unless Otherwise Specified	<b>Limits</b> D Suffix -40 to 85°C					
Parameter	Symbol	DISCHARGE = $-V_{IN}$ = 0 V, $V_{CC}$ = 10 V + $V_{IN}$ = 48 V, $R_{BIAS}$ = 390 k $\Omega$ $R_{OSC}$ = 330 k $\Omega$	<b>Temp</b> <sup>b</sup>	Min <sup>d</sup>	Тур	Max <sup>d</sup>	Unit	
Reference								
Output Voltage	V <sub>R</sub>	OSC IN = - $V_{IN}$ (OSC Disabled) $R_L = 10 \text{ M}\Omega$	Room Full	3.92 3.85	4.0	4.08 4.15	V	
Output Impedance <sup>e</sup>	Z <sub>OUT</sub>		Room	15	30	45	kΩ	
Short Circuit Current	I <sub>SREF</sub>	$V_{REF} = -V_{IN}$	Room	70	100	130	μΑ	
Temperature Stability <sup>e</sup>	Т		Full		0.25	1.0	mV/°C	
Long Term Stability <sup>e</sup>	T <sub>REF</sub>	t = 1000 hrs., T <sub>A</sub> = 125°C	Room		5	25	mV	
Oscillator								
Maximum Frequency <sup>e</sup>	f <sub>MAX</sub>	R <sub>OSC</sub> = 0	Room	1	3		MHz	
Initial Assurance	fosc	$R_{OSC} = 330 \text{ k}\Omega^{f}$	Room	80	100	120	- kHz	
Initial Accuracy		$R_{OSC} = 150 \text{ k}\Omega^{f}$	Room	160	200	240		
Voltage Stability	Δf/f	$\Delta f/f = f(13.5 \text{ V}) - f(10 \text{ V}) / f(10 \text{ V})$	Room	4	10	15	%	
Temperature Coefficient <sup>e</sup>	T <sub>OSC</sub>		Full		200	500	ppm/ °C	
Error Amplifier								
Feedback Input Voltage	V <sub>FB</sub>	FB Tied to COMP OSC IN = - V <sub>IN</sub> (OSC Disabled)	Room	3.96	4.00	4.04	V	
Input BIAS Current	I <sub>FB</sub>	OSC IN = - V <sub>IN</sub> , V <sub>FB</sub> = 4 V	Room		25	500	nA	
Input OFFSET Voltage	V <sub>OS</sub>		Room		±15	±40	mV	
Open Loop Voltage Gain <sup>e</sup>	A <sub>VOL</sub>	Room 60		80		dB		
Unity Gain Bandwidth <sup>e</sup>	BW	OSC IN = - V <sub>IN</sub> (OSC Disabled)	Room	0.7	1		MHz	
Dynamic Output Impedance <sup>e</sup>	Z <sub>OUT</sub>		Room		1000	2000	Ω	
Output Current	Гоит	Source (V <sub>FB</sub> = 3.4 V)	Room		-2.0	-1.4	-1.4 mA	
Output Guitetit		Sink (V <sub>FB</sub> = 4.5 V)	Room	0.12	0.15			
Power Supply Rejection	PSRR	10 V ≤ V <sub>CC</sub> ≤ 13.5 V	Room	50	70		dB	



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	Symbol	Test Conditions Unless Otherwise Specified DISCHARGE = -V <sub>IN</sub> = 0 V, V <sub>CC</sub> = 10 V	Limits D Suffix -40 to 85°C					
Parameter		$+V_{IN} = 48 \text{ V}, R_{BIAS} = 390 \text{ k}\Omega$ $R_{OSC} = 330 \text{ k}\Omega$	<b>Temp</b> <sup>b</sup>	<b>Min</b> <sup>d</sup>	Турс	Max <sup>d</sup>	Unit	
Current Limit								
Threshold Voltage	V <sub>SOURCE</sub>	$R_L$ = 100 $\Omega$ from DRAIN to $V_{CC}$ , $V_{FB}$ = 0 $V$	Room	1.0	1.2	1.4	V	
Delay to Output	t <sub>d</sub>	$R_L$ = 100 $\Omega$ from DRAIN to $V_{CC}$ $V_{SOURCE}$ = 1.5 V, See Figure 1.	Room		100	200	ns	
Pre-Regulator/Start-Up								
Input Voltage	+V <sub>IN</sub>	I <sub>IN</sub> = 10 μA	Room	120			V	
Input Leakage Current	+I <sub>IN</sub>	V <sub>CC</sub> ≥ 10 V	Room			10	μΑ	
Pre-Regulator Start-Up Current	I <sub>START</sub>	Pulse Width ≤ 300 μs, V <sub>CC</sub> = 7 V	Room	8	15		mA	
V <sub>CC</sub> Pre-Regulator Turn-Off Threshold Voltage	$V_{REG}$	I <sub>PRE-REGULATOR</sub> = 10 μA	Room	7.8	9.4	9.8		
Undervoltage Lockout	V <sub>UVLO</sub>	$R_L = 100 \Omega$ from DRAIN to $V_{CC}$ See Detailed Description	Room	7.0	8.8	9.3	V	
V <sub>REG</sub> - V <sub>UVLO</sub>	V <sub>DELTA</sub>		Room	0.3	0.6			
Supply								
Supply Current	I <sub>CC</sub>		Room	0.45	0.6	1.0	mA	
Bias Current	I <sub>BIAS</sub>		Room	10	15	20	μΑ	
Logic								
SHUTDOWN Delay <sup>e</sup>	t <sub>SD</sub>	V <sub>SOURCE</sub> = -V <sub>IN</sub> , See Figure 2.	Room		50	100		
SHUTDOWN Pulse Width <sup>e</sup>	t <sub>SW</sub>		Room	50				
RESET Pulse Width <sup>e</sup>	$t_{RW}$	O Firm	Room	50			ns	
Latching Pulse Width <sup>e</sup> SHUTDOWN and RESET Low	$t_{LW}$	See Figure 3.		25				
Input Low Voltage	$V_{IL}$	Room				2.0	\/	
Input High Voltage	$V_{IH}$		Room	8.0			V	
Input Current Input Voltage High	I <sub>IH</sub>	V <sub>IN</sub> = V <sub>CC</sub>	Room		1	5	μΑ	
Input Current Input Voltage Low	I <sub>IL</sub>	V <sub>IN</sub> = 0 V	Room	-35	-25			
MOSFET Switch								
Breakdown Voltage	V <sub>BR(DSS)</sub>	I <sub>DRAIN</sub> = 100 μA	Full	200	220		V	
Drain-Source On-Resistance <sup>g</sup>	r <sub>DS(on)</sub>	I <sub>DRAIN</sub> = 100 mA	Room		3	5	Ω	
Drain Off Leakage Current	I <sub>DSS</sub>	V <sub>DRAIN</sub> = 150 V	Room		5	10	μΑ	
Drain Capacitance <sup>e</sup>	C <sub>DS</sub>		Room		35		pF	

#### Notes

- a. Refer to PROCESS OPTION FLOWCHART for additional information.
- b. Room = 25°C, Cold and Hot = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.
- f.  $C_{STRAY}$  @ OSC IN  $\leq$  5 pF.
- g. Temperature coefficient of  $r_{\mbox{\footnotesize{DS}}(\mbox{\footnotesize{on}})}$  is 0.75% per °C, typical.

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#### **TIMING WAVEFORMS**



FIGURE 1. FIGURE 2.

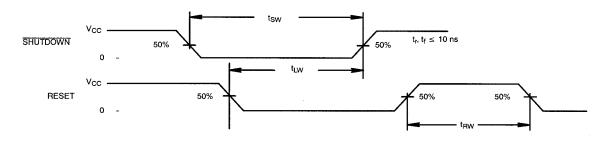
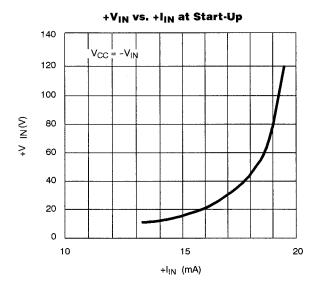


FIGURE 3.

#### TYPICAL CHARACTERISTICS



Output Switching Frequency
vs. Oscillator Resistance

1 M

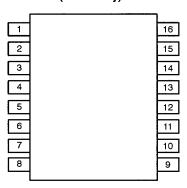
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FIGURE 4. FIGURE 5.



#### **PIN CONFIGURATIONS**

# SO-16 (Wide-Body)



Top View Order Number: Si9104DW

N DESCRIPTION					
	Pin Number				
Function	14-Pin Plastic DIP	16-Pin SOIC	20-Pin PLCC		
SOURCE	4	1	7		
-V <sub>IN</sub>	5	2	8		
V <sub>CC</sub>	6	4	9		
OSC <sub>OUT</sub>	7	5	10		
OSC <sub>IN</sub>	8	6	11		
DISCHARGE	9	7	12		
$V_{REF}$	10	8	14		
SHUTDOWN	11	9	16		
RESET	12	10	17		
COMP	13	11	18		
FB	14	12	20		
BIAS	1	13	2		
+V <sub>IN</sub>	2	14	3		
DRAIN	3	16	5		
NC		3, 15	1, 4, 6, 13, 15, 19		

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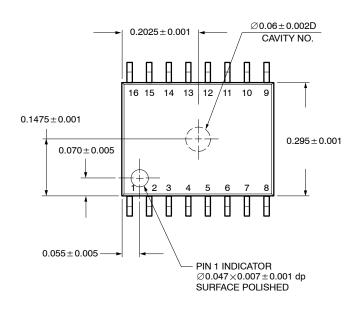
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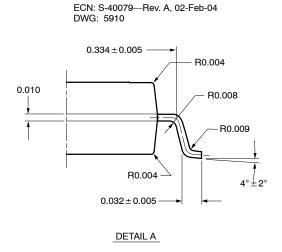
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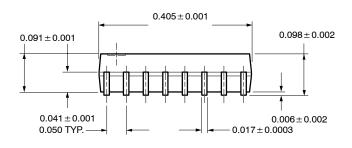
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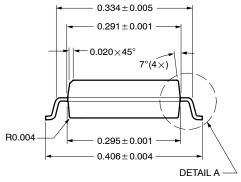


#### SOIC (WIDE-BODY): 16-LEAD (POWER IC ONLY)









All Dimensions In Inches



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Revision: 02-Oct-12 Document Number: 91000